## NSN 5961-01-040-6424

A110a0

Mil-std (military Standard):

Mil-prf-19500 spec.

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-040-6424 **Inclosure Material:** Metal **Overall Length:** Between 0.250 inches and 0.450 inches Overall Diameter: 0.875 inches **Mounting Facility Quantity: Mounting Method:** Unthreaded hole **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 24.0 reverse gate to source breakdown voltage torr **Current Rating Per Characteristic:** 520.00 milliamperes reverse surge current **Power Rating Per Characteristic:** 50.0 watts total power dissipation **Maximum Operating Tempurature Per Measurement Point:** 150.0 inlet swivel per square foot **Test Data Document:** 81349-mil-prf-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.). **Terminal Type And Quantity:** 2 uninsulated wire lead **Specification Data:** 81349-mil-prf-19500/114 government specification Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: